

## Supporting Information (SI)

# Grain Structure–Controlled Growth of InSb Crystals: a Grain Boundary Engineering Approach for Enhanced Thermoelectric Performance

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## 1. Morphological and elemental compositional investigation of the prepared InSb Ingots.

Fig. S1 (a<sub>1</sub>-c<sub>3</sub>) shows the FESEM images of the prepared ingots SC InSb (a<sub>1</sub>-a<sub>3</sub>), AQ InSb (b<sub>1</sub>-b<sub>3</sub>), and IWQ InSb (c<sub>1</sub>-c<sub>3</sub>) samples.

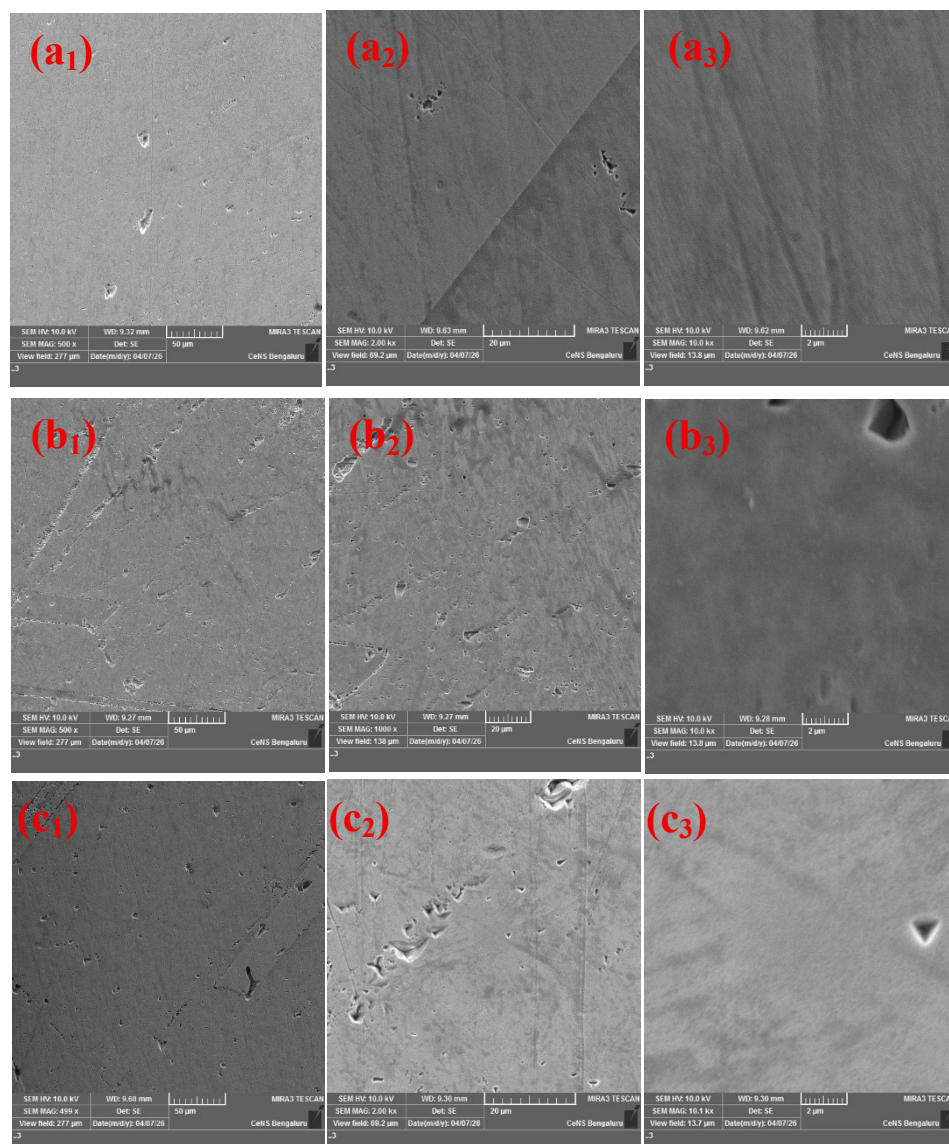
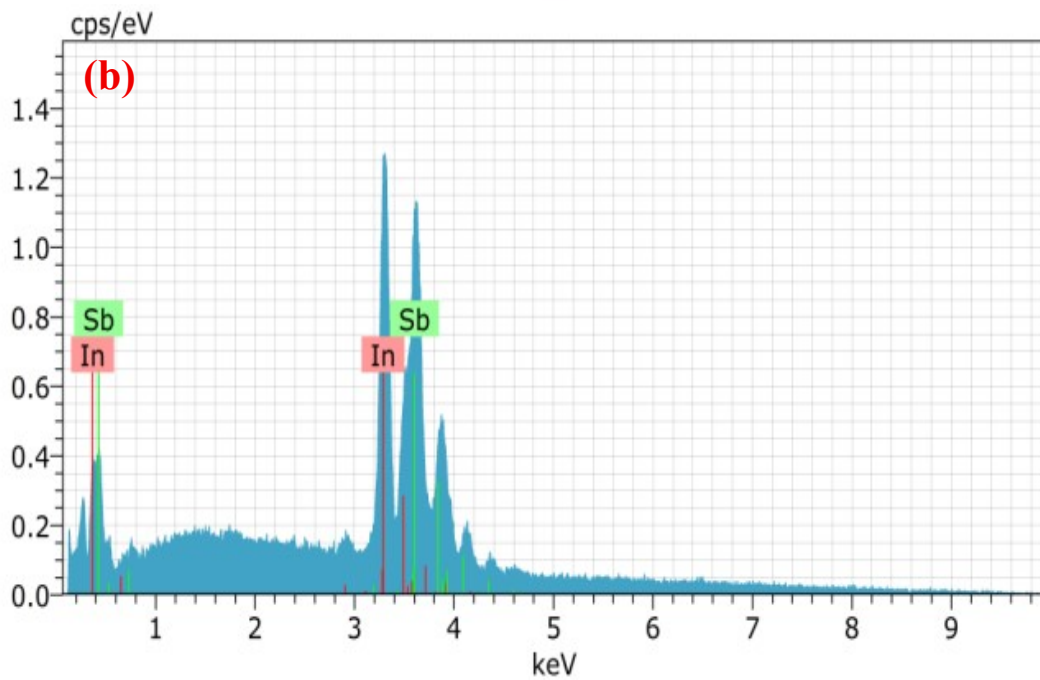
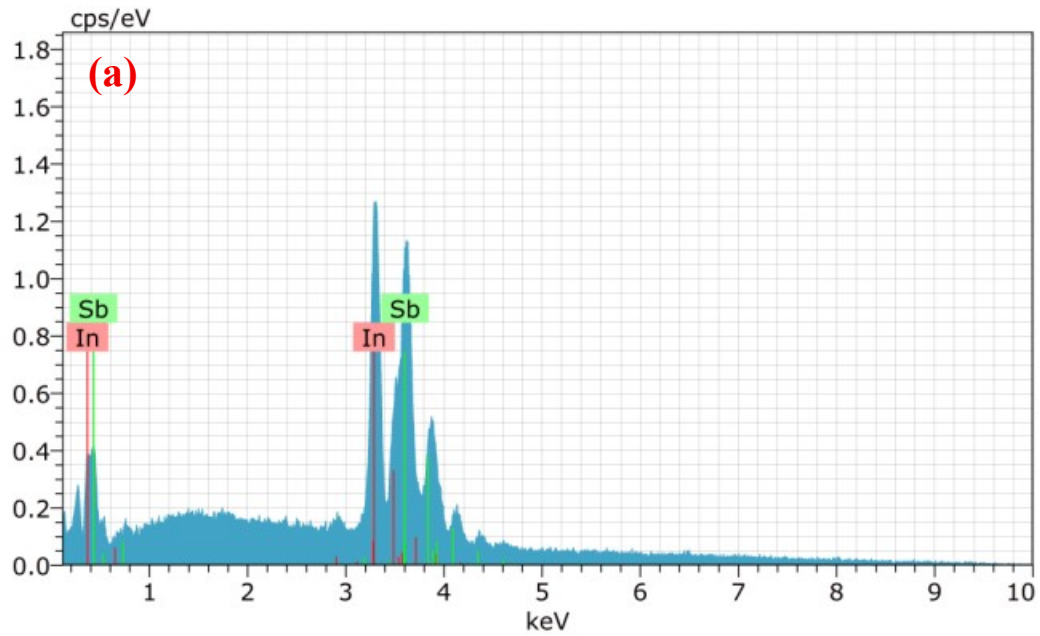


Fig. S1: FESEM pictures of SC InSb ( $a_1$ - $a_3$ ), AQ InSb ( $b_1$ - $b_3$ ), and IWQ InSb ( $c_1$ - $c_3$  polished ingots).

Fig. S2 shows the EDX analysis of SC InSb (a), AQ InSb (b), IWQ InSb (c), samples. From the EDX Spectrum the presence of In and Sb was confirmed the InSb samples. The low-level oxygen peaks related to surface oxidation of the samples. The reason for carbon peak was the double side carbon tape was used to load the samples. The elemental compositions of all the



samples are revealed in Table T1.

(c)

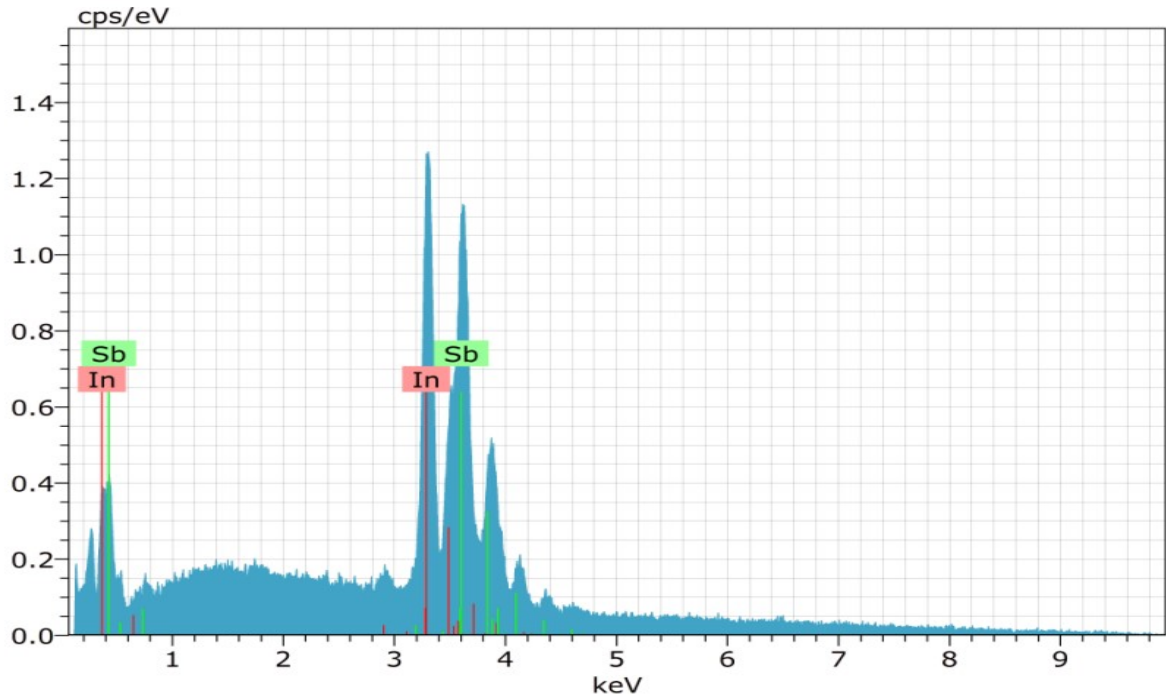
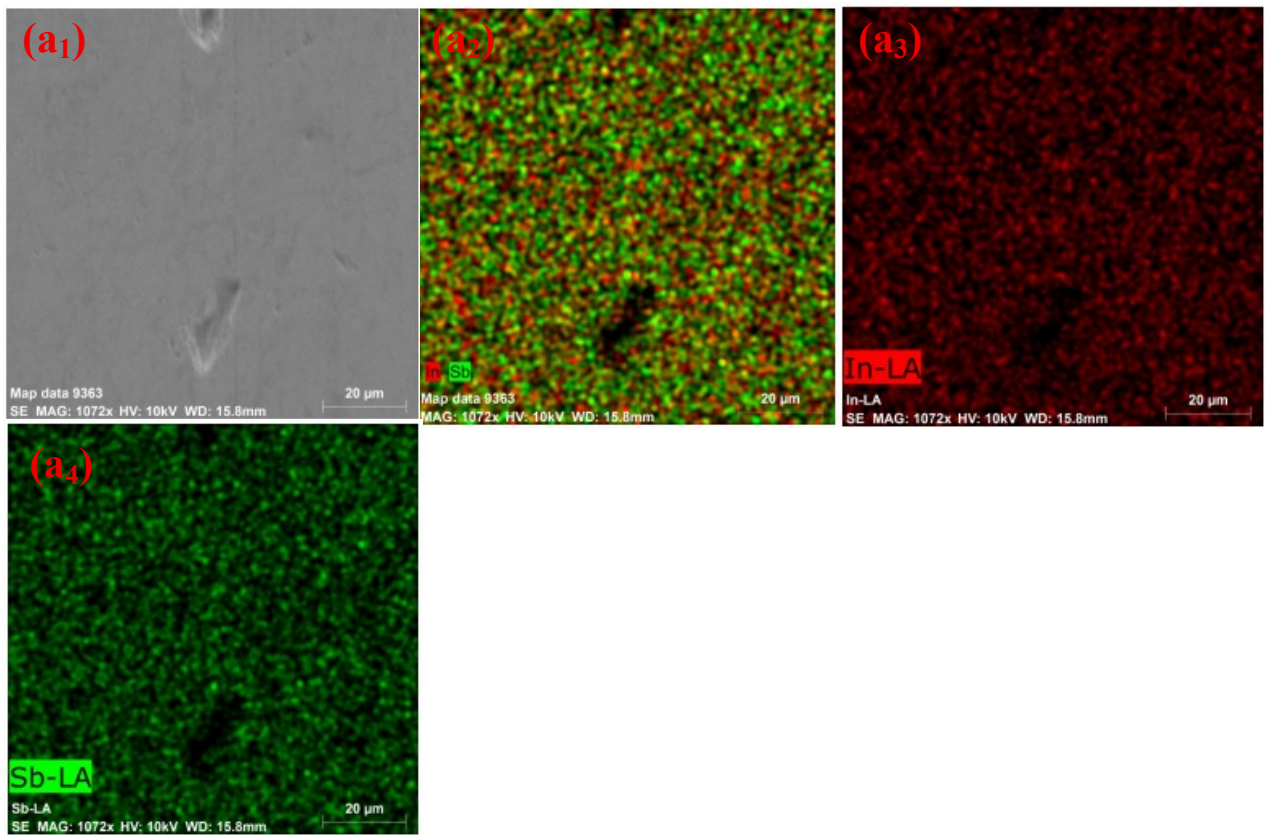


Fig. S2: EDX analysis of SC InSb (a), AQ InSb (b), IWQ InSb (c), samples.

**Table T1:** EDX - elemental compositional investigation of SC InSb (a), AQ InSb (b), IWQ InSb (c), samples.

Sample	Element	Weight %	Atomic %
SC InSb	In	46.29	47.75
	Sb	53.71	52.25
AQ InSb	In	46.19	47.55
	Sb	53.81	52.45
IWQ InSb	In	46.09	47.15
	Sb	53.91	52.85

Fig. S3 shows the FE-SEM basic elemental mapping analysis of the SC InSb ( $a_1$ - $a_3$ ), AQ InSb ( $b_1$ - $b_3$ ), and IWQ InSb ( $c_1$ - $c_3$ ) samples. The elemental mapping analysis validates the overall spreading of In and Sb elements in each InSb polycrystalline ingots.



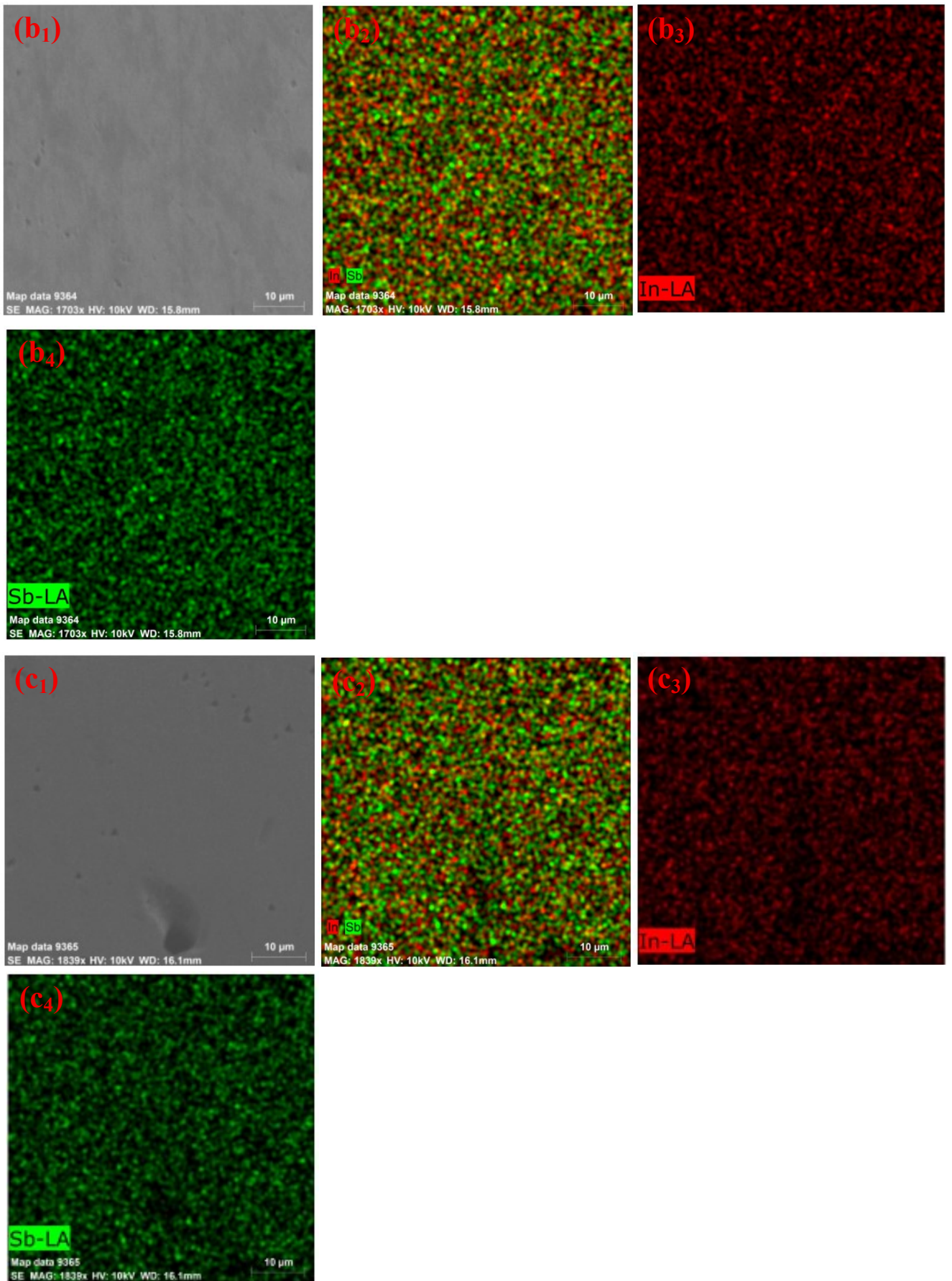


Fig. S3: FE-SEM elemental mapping analysis of the SC InSb (a<sub>1</sub>-a<sub>4</sub>) AQ InSb (b<sub>1</sub>-b<sub>4</sub>) and IWQ InSb (c<sub>1</sub>-c<sub>4</sub>).

Table S4  
boundary

(a): grain  
character

<b>Sc InSb (Boundaries CSL)</b>						
<b>Parameters</b>	<b>Centre portions</b>			<b>Edge portions</b>		
	$\Sigma 3$	$\Sigma 9$	summary	$\Sigma 3$	$\Sigma 9$	summary
<b>Tolerance</b>	8.66	5.00	-	8.66	5.00	-
<b>Fraction</b>	0.559	0.263	0.822	0.987	0.013	1.000
<b>volume</b>	0.0176	0.0102	0.0444	0.0176	0.0102	0.0444
<b>MDF Value</b>	31.81	25.91	18.51	56.19	1.28	22.53
<b>Number</b>	1589	748	-	836	11	-
<b>Length</b>	2.29 cm	1.07 cm	-	1.20 cm	158.77 microns	-
<b>Lower angle (<math>\Sigma 3, \Sigma 9</math>) grain boundaries</b>						

distributions of SC InSb sample.

<b>AQ InSb (Boundaries CSL)</b>											
<b>Parameters</b>	<b>Centre portions</b>					<b>Edge portions</b>					
	$\Sigma 3$	$\Sigma 9$	$\Sigma 27a$	$\Sigma 27b$	summary	$\Sigma 3$	$\Sigma 9$	$\Sigma 27a$	$\Sigma 27b$	$\Sigma 19a$	summary
<b>Tolerance</b>	<b>8.66</b>	<b>5.00</b>	<b>2.89</b>	<b>2.89</b>	-	8.66	5.00	2.89	2.89	3.44	-
<b>Fraction</b>	0.582	0.108	0.059	0.041	0.789	0.374	0.105	0.119	0.004	0.002	0.604
<b>volume</b>	0.0176	0.0102	0.0020	0.0039	0.0444	0.0176	0.0102	0.0020	0.0039	0.0022	0.0444
<b>MDF Value</b>	33.15	10.59	30.07	10.40	17.78	21.28	10.39	60.79	1.06	0.55	13.61
<b>Number</b>	2795	516	282	195	-	1630	460	518	18	8	-
<b>Length</b>	4.03 cm	7.44 mm	4.07 mm	2.81 mm	-	2.35 cm	6.63 mm	7.47 mm	259.80 microns	115.47 microns	-
<b>Lower angle (<math>\Sigma 3, \Sigma 9</math>) and Higher angle (<math>\Sigma 27a, \Sigma 27b, \Sigma 19a</math>) grain boundaries</b>											

Table S4 (b): grain boundary character distributions of AQ InSb sample.

Table S4 (c): grain boundary character distributions of IWQ InSb sample.

**IWQ InSb (Boundaries CSL)**

Parameters	Centre portions							Edge portions					
	$\Sigma 3$	$\Sigma 9$	$\Sigma 27a$	$\Sigma 27b$	$\Sigma 35b$	$\Sigma 19b$	summary	$\Sigma 3$	$\Sigma 9$	$\Sigma 27a$	$\Sigma 27b$	$\Sigma 19a$	summary
<b>Tolerance</b>	8.66	5.00	2.89	2.89	2.54	3.44	-	8.66	5.00	2.89	2.89	3.44	-
<b>Fraction</b>	0.531	0.077	0.038	0.019	0.005	0005	0.675	0.564	0.099	0.045	0.032	0.001	0.742
<b>volume</b>	0.0176	0.0102	0.0020	0.0039	0.0026	0.0022	0.0444	0.0176	0.0102	0.0020	0.0039	0.0033	0.0444
<b>MDF Value</b>	30.25	7.59	19.27	4.95	1.79	2.10	15.21	32.12	9.75	22.86	8.20	0.44	16.71
<b>Number</b>	5957	863	422	217	53	52	-	8932	1566	707	507	23	-
<b>Length</b>	8.59 cm	1.24 cm	6.09 mm	3.13 mm	764.98 mm	750.55 microns	-	12.89 cm	2.260 cm	1.02 cm	7.31 mm	331.97 microns	-

**Lower angle ( $\Sigma 3, \Sigma 9$ ) and Higher angle ( $\Sigma 27a, \Sigma 27b, \Sigma 35b, \Sigma 19b$ ) grain boundaries**